## SN54S8003, SN74S8003 **DUAL 2-INPUT POSITIVE-NAND GATES**

SN74S8003 . . . D OR P PACKAGE (TOP VIEW)

1A

1BП

GND

2 1Y**[**]3

4

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8 [] V<sub>CC</sub>

7 🛿 2B

6 🛛 2A

5 2Y

- Typical V<sub>OLP</sub> (Output Ground Bounce) < 1 V</li> at  $V_{CC} = 5 \overline{V}$ ,  $T_A = 25^{\circ}C$
- Package Options Include Plastic **Small-Outline Packages and Plastic DIPs**

## description

The 'S8003 contains two independent 2-input NAND gates. It performs the Boolean functions  $Y = \overline{A \cdot B}$  or  $Y = \overline{A} + \overline{B}$  in positive logic.

The SN54S8003 is characterized for operation over the full military temperature range of -55°C to 125°C. The SN74S8003 is characterized for operation from 0°C to 70°C.

FUNCTION TABLE (each gate)							
INP	UTS	OUTPUT					
Α	В	Y					
Н	Н	L					
L	Х	Н					
Х	L	н					

### logic symbol<sup>†</sup>





logic diagram (positive logic)

<sup>†</sup> This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>‡</sup>

Supply voltage, V <sub>CC</sub>		
Input voltage, V <sub>I</sub>		5.5 V
	SN54S8003	
	SN74S8003	0°C to 70°C
Storage temperature range		–65°C to 150°C

<sup>‡</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.



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### recommended operating conditions

		SN54S8003			SN74S8003			UNIT	
		MIN	NOM	MAX	MIN	NOM	MAX	UNIT	
VCC	Supply voltage	4.5	5	5.5	4.75	5	5.25	V	
VIH	High-level input voltage	2			2			V	
VIL	Low-level input voltage			0.8			0.8	V	
IOH	High-level output current			-1			-1	mA	
IOL	Low-level output current			20			20	mA	
TA	Operating free-air temperature	-55		125	0		70	°C	

# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS <sup>T</sup>			S	SN54S8003			SN74S8003		
				MIN	TYP‡	MAX	MIN	TYP‡	MAX	UNIT
VIK	$V_{CC} = MIN,$	lj = -18 mA				-1.2			-1.2	V
VOH	$V_{CC} = MIN,$	V <sub>IL</sub> = 0.8 V,	I <sub>OH</sub> = -1 mA	2.5	3.4		2.7	3.4		V
VOL	$V_{CC} = MIN,$	V <sub>IH</sub> = 2 V,	I <sub>OL</sub> = 20 mA			0.5			0.5	V
Ц	V <sub>CC</sub> = MAX,	V <sub>I</sub> = 5.5 V				1			1	mA
ЧН	V <sub>CC</sub> = MAX,	V <sub>I</sub> = 2.7 V				50			50	μΑ
١ <sub>IL</sub>	V <sub>CC</sub> = MAX,	V <sub>I</sub> = 0.5 V				-2			-2	mA
IOS§	$V_{CC} = MAX$			-40		-100	-40		-100	mA
Іссн	V <sub>CC</sub> = MAX,	V <sub>1</sub> = 0			6	10		6	10	mA
ICCL	V <sub>CC</sub> = MAX,	V <sub>I</sub> = 4.5 V			14	20		14	20	mA

<sup>†</sup> For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

<sup>‡</sup> All typical values are at  $V_{CC} = 5 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .

§ Not more than one output should be shorted at a time, and the duration of the short-circuit should not exceed one second.

## switching characteristics, $V_{CC} = 5 V$ , $T_A = 25^{\circ}C$ (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CO	MIN	ТҮР	МАХ	UNIT	
<sup>t</sup> PLH	A or B	Y	R <sub>L</sub> = 280 Ω,	C <sub>L</sub> = 15 pF		3	4.5	ns
<sup>t</sup> PHL						3	5	115
<sup>t</sup> PLH			R <sub>L</sub> = 280 Ω,	C <sub>1</sub> = 50 pF		4.5		ns
<sup>t</sup> PHL				0L = 30 bi		5		110



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### PARAMETER MEASUREMENT INFORMATION

NOTES: A.  $C_L$  includes probe and jig capacitance.

- B. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz, Z<sub>0</sub> = 50  $\Omega$ , t<sub>f</sub>  $\leq$  2.5 ns, t<sub>f</sub>  $\leq$  2.5 ns.
- C. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.

D. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms



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